Review of: "chemical stability and high corrosion resistance excellent, and high special resistance of nano-electricity, they have good electromagnetic and nano-magneto-optic properties"

Jorge Gasperini[1]

1 University of Rome Tor Vergata

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The advantages of using nanoporous aluminum oxide as a template for the production of nanowires compared to other methods, including the high order of pores, the alignment of pores, and the controllability of the ratio The length is equal to the diameter and high density of the porosity.

> *The amount of order and dimensions of the nanowires produced using this set of templates is determined and controlled by the initial conditions of the anodizing process.*

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